

1. General description

Ultrafast dual epitaxial rectifier diode in a SOT78 (TO-220AB) plastic package.

2. Features and benefits

- High reverse voltage surge capability
- High thermal cycling performance
- Low thermal resistance
- Very low on-state loss
- · Soft recovery characteristic minimizes power consuming oscillations

3. Applications

• Output rectifiers in high-frequency switched-mode power supplies

4. Quick reference data

Symbol	Parameter Conditions Values						Unit
		Conditions	onditions values				
Absolute	maximum rating						
V_{RRM}	repetitive peak reverse voltage		150			V	
I _{O(AV)}	average output current	δ = 0.5; square-wave pulse; T _{mb} ≤ 115 °C; both diodes conducting; <u>Fig. 1</u> ; <u>Fig. 2</u>	20				A
I _{RRM}	repetitive peak reverse current	$δ = 0.001; t_p = 2 μs;$	0.2			A	
V_{ESD}	electrostatic discharge voltage	HBM; C = 250 pF; R = 1.5 k Ω ; all pins	8		kV		
I _{FRM}	repetitive peak forward current	δ = 0.5; t _p = 25 μs; T _{mb} ≤ 115 °C; per diode	20		A		
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; sine-wave pulse; $T_{j(init)}$ = 25 °C; per diode	125		A		
		t_p = 8.3 ms; sine-wave pulse; $T_{j(init)}$ = 25 °C; per diode	137			A	
Symbol	Parameter	Conditions	Min Typ Max		Max	Unit	
Static ch	aracteristics	· · · · · ·					
V _F	forward voltage	I _F = 8 A; T _j = 150 °C; <u>Fig. 4</u>	- 0.72 0.85		0.85	V	
Dynamic	characteristics						
t _{rr}	reverse recovery time	$I_F = 1 \text{ A}; V_R = 30 \text{ V}; dI_F/dt = 100 \text{ A}/\mu\text{s};$ $T_j = 25 \text{ °C}; \text{ ramp recovery; Fig. 5}$		-	20	25	ns
		$I_F = 0.5 \text{ A to } I_R = 1 \text{ A}; T_j = 25 \text{ °C};$ measured at $I_R = 0.25 \text{ A};$ step recovery; Fig. 6		-	10	20	ns

5. Pinning information

Pin	Pinning infor Symbol	Description	Simplified outline	Graphic symbol
1	A1	anode 1	mb	
2	К	cathode	P ⊖ f	
3	A2	anode 2		
mb	К	mounting base; cathode		K sym125

6. Ordering information

Table 3. Ordering info	ormation		
Type number Package			
	Name	Description	Version
BYV32E-150	TO-220AB	plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB	SOT78

7. Marking

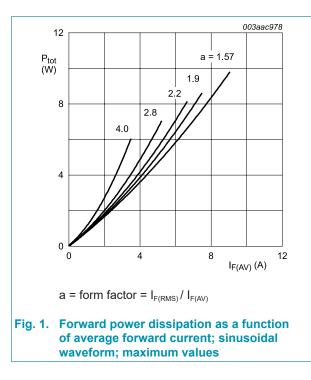
Table 4. Marking codes						
Type number	Marking codes					
BYV32E-150	BYV32E-150					

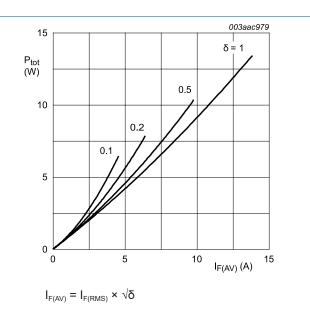
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Values	Unit
V _{RRM}	repetitive peak reverse voltage		150	V
V_{RWM}	crest working reverse voltage		150	V
V _R	reverse voltage	DC	150	V
I _{O(AV)}	average output current	δ = 0.5; square-wave pulse; T _{mb} ≤ 115 °C; both diodes conducting; <u>Fig 1</u> ; <u>Fig 2</u>	20	A
I _{FRM}	repetitive peak forward current	δ = 0.5; t _p = 25 μs; T _{mb} ≤ 115 °C; per diode	20	A
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; sine-wave pulse; $T_{j(init)}$ = 25 °C; per diode	125	A
		t_p = 8.3 ms; sine-wave pulse; $T_{j(init)}$ = 25 °C; per diode	137	A
I _{RRM}	repetitive peak reverse current	δ = 0.001; t _p = 2 µs; per diode	0.2	A
I _{RSM}	non-repetitive peak reverse current	t_p = 100 µs; per diode	0.2	A
T _{stg}	storage temperature		-40 to 150	°C
Tj	junction temperature		150	°C
V_{ESD}	electrostatic discharge voltage	HBM; all pins; C = 250 pF; R = 1.5 k Ω	8	kV

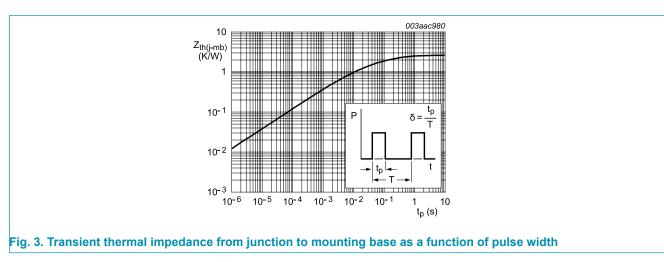






9. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{\text{th(j-mb)}}$	thermal resistance from junction to	with heatsink compound; both diodes conducting	-	-	1.6	K/W
	mounting base	with heatsink compound; per diode; <u>Fig 3</u>	-	-	2.4	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient		-	60	-	K/W

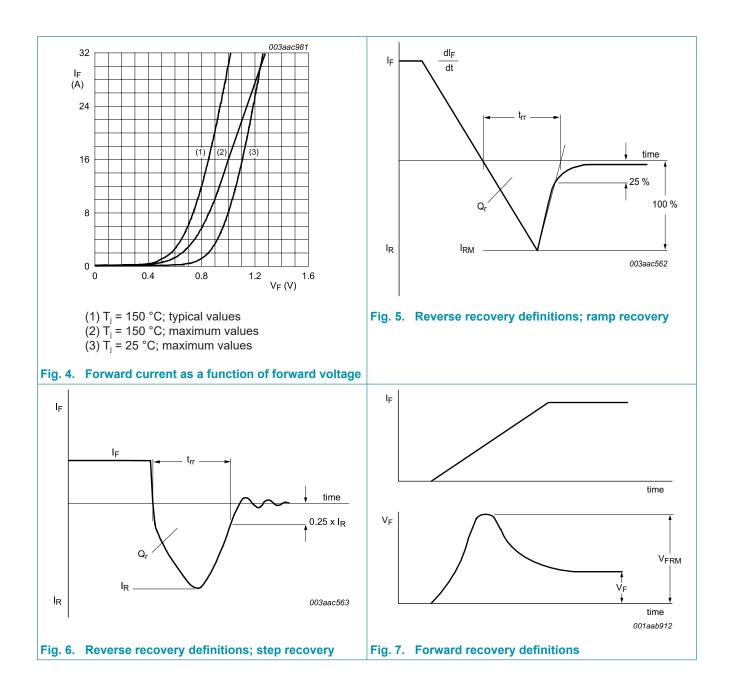


10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics					
V _F	forward voltage	I _F = 8 A; T _j = 150 °C; <u>Fig. 4</u>	-	0.72	0.85	V
		I _F = 20 A; T _j = 25 °C	-	1	1.15	V
I _R	reverse current	V _R = 150 V; T _j = 25 °C	-	6	30	μA
		V _R = 150 V; T _j = 100 °C	-	0.2	0.6	mA
Dynamic	characteristics					
Q _r	recovered charge	I_{F} = 2 A; V_{R} = 30 V; dI_{\text{F}}/dt = 20 A/µs; T_{j} = 25 °C	-	8	12.5	nC
t _{rr}	reverse recovery time	I _F = 1 A; V _R = 30 V; dI _F /dt = 100 A/μs; T _j = 25 °C; ramp recovery; <u>Fig. 5</u>	-	20	25	ns
		$I_{\rm F}$ = 0.5 A to $I_{\rm R}$ = 1 A; $T_{\rm j}$ = 25 °C; measured at $I_{\rm R}$ = 0.25 A; step recovery; <u>Fig. 6</u>	-	10	20	ns
V_{FR}	forward recovery voltage	I _F = 1 A; dI _F /dt = 10 A/μs; T _j = 25 °C; <u>Fig. 7</u>	-	-	1	V

BYV32E-150

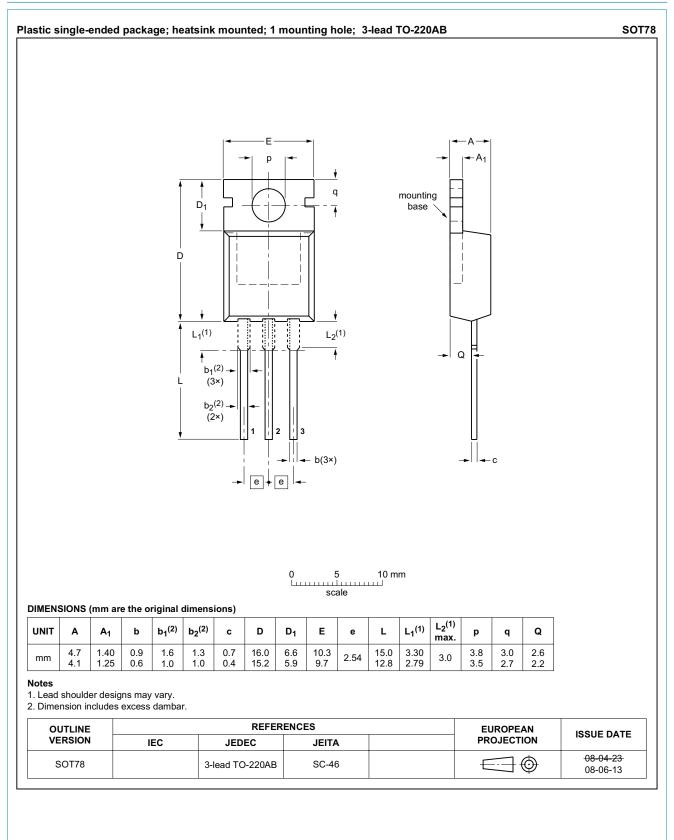
Dual rugged ultrafast rectifier diode, 20 A, 150 V



BYV32E-150

Dual rugged ultrafast rectifier diode, 20 A, 150 V

11. Package outline



BYV32E-150 Product data sheet

12. Revision history

Table 8. Revision history	/						
Document ID	Release date	Data sheet status	Change notice	Supersedes			
BYV32E-150 v.5	20180307	Product specification	-	BYV32E-150_4			
Modifications: Change from NXP version to WeEn version							
BYV32E-150_4	20090302	Product specification	-	BYV32E_SERIES_3			
 Modifications: The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors. Legal texts have been adapted to the new company name where appropriate. Package outline updated. Type number BYV32E-150 separated from data sheet BYV32E SERIES 3 							
BYV32E_SERIES_3	20010301	Product specification	-	BYV32E_SERIES_2			
BYV32E_SERIES_2	19980701	Product specification	-	BYV32EB_SERIES_1			
BYV32EB_SERIES_1	19960801	Product specification	-	-			

BYV32E-150

Dual rugged ultrafast rectifier diode, 20 A, 150 V

13. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
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